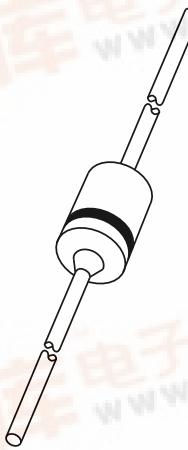


DATA SHEET



BYD63

Ripple blocking diode

Product specification

1996 Jun 10

Supersedes data of November 1995

File under Discrete Semiconductors, SC01

Ripple blocking diode

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FEATURES

- Glass passivated
- High maximum operating temperature
- Low leakage current
- Excellent stability
- Guaranteed minimum turn-on time for absorbing forward current transients and oscillations
- Specially designed as rectifier in the auxiliary power supply in e.g. switched mode power supplies
- Available in ammo-pack.

DESCRIPTION

Cavity free cylindrical glass package through Implotec™⁽¹⁾ technology. This package is hermetically sealed

and fatigue free as coefficients of expansion of all used parts are matched.

(1) Implotec is a trademark of Philips.

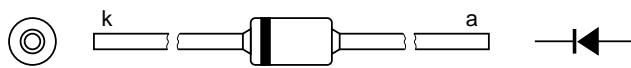


Fig.1 Simplified outline (SOD81) and symbol.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{RRM}	repetitive peak reverse voltage		–	300	V
V_R	continuous reverse voltage		–	300	V
$I_{F(AV)}$	average forward current	averaged over any 20 ms period; $T_{tp} = 55^\circ\text{C}$; lead length = 10 mm; see Fig.2; see also Fig.4	–	0.85	A
		averaged over any 20 ms period; $T_{amb} = 65^\circ\text{C}$; PCB mounting (Fig.8); see Fig.3; see also Fig.4	–	0.45	A
I_{FRM}	repetitive peak forward current	$T_{tp} = 55^\circ\text{C}$	–	8.25	A
		$T_{amb} = 65^\circ\text{C}$	–	4.45	A
I_{FSM}	non-repetitive peak forward current	$t = 10\text{ ms}$ half sine wave; $T_j = T_{j\max}$ prior to surge; $V_R = V_{RRM\max}$	–	5	A
T_{stg}	storage temperature		–65	+175	$^\circ\text{C}$
T_j	junction temperature		–65	+175	$^\circ\text{C}$

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ELECTRICAL CHARACTERISTICS

 $T_j = 25^\circ\text{C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_F	forward voltage	$I_F = 1 \text{ A}; T_j = T_{j\max};$ see Fig.5	–	–	1.7	V
		$I_F = 1 \text{ A};$ see Fig.5	–	–	2.3	V
I_R	reverse current	$V_R = V_{RRM\max};$ see Fig.6	–	–	1	μA
		$V_R = V_{RRM\max}; T_j = 165^\circ\text{C};$ see Fig.6	–	–	100	μA
t_{fr}	forward recovery time	when switched to $I_F = 1 \text{ A}$ in 50 ns; see Fig.9	–	–	350	ns
t_{on}	turn-on time	when switched from $V_F = 0 \text{ V}$ to $V_F = 3 \text{ V};$ measured between 10% and 90% of $I_F\max;$ see Fig.11	500	–	–	ns
t_{rr}	reverse recovery time	when switched from $I_F = 0.5 \text{ A}$ to $I_R = 1 \text{ A};$ measured at $I_R = 0.25 \text{ A};$ see Fig.11	–	–	150	ns
C_d	diode capacitance	$f = 1 \text{ MHz}; V_R = 0 \text{ V};$ see Fig.7	–	17	–	pF

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j\cdot tp}$	thermal resistance from junction to tie-point	lead length = 10 mm	60	K/W
$R_{th\ j\cdot a}$	thermal resistance from junction to ambient	note 1	120	K/W

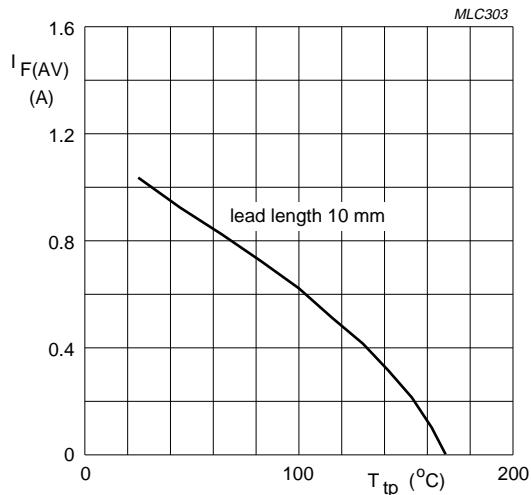
Note

1. Device mounted on an epoxy-glass printed-circuit board, 1.5 mm thick; thickness of Cu-layer $\geq 40 \mu\text{m}$, see Fig.8. For more information please refer to the 'General Part of Handbook SC01.'

Ripple blocking diode

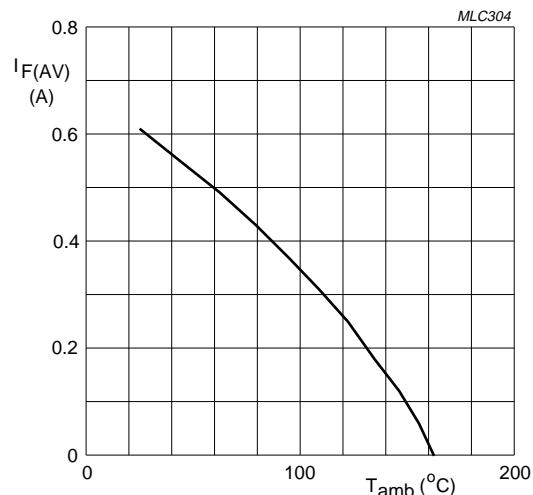
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GRAPHICAL DATA



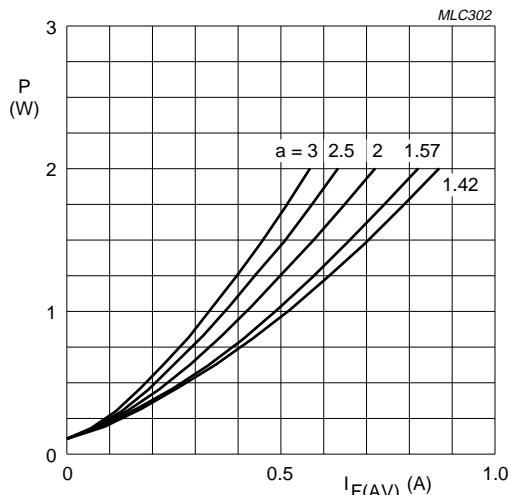
$a = 1.42$; $V_R = V_{RRMmax}$; $\delta = 0.5$.
Switched mode application.

Fig.2 Maximum permissible average forward current as a function of tie-point temperature (including losses due to reverse leakage).



$a = 1.42$; $V_R = V_{RRMmax}$; $\delta = 0.5$.
Device mounted as shown in Fig.8.
Switched mode application.

Fig.3 Maximum permissible average forward current as a function of ambient temperature (including losses due to reverse leakage).



$a = I_{F(RMS)}/I_{F(AV)}$; $V_R = V_{RRMmax}$; $\delta = 0.5$.

Fig.4 Maximum steady state power dissipation (forward plus leakage current losses, excluding switching losses) as a function of average forward current.

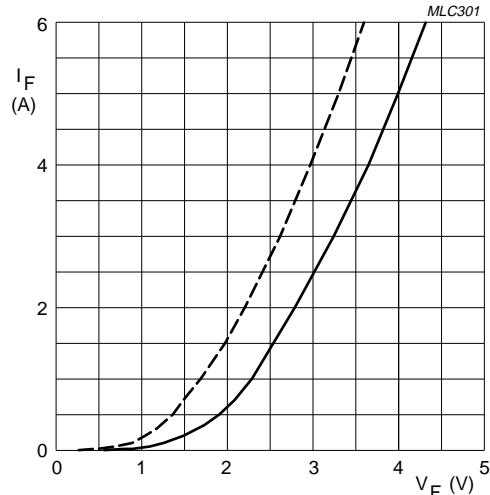


Fig.5 Forward current as a function of forward voltage; maximum values.

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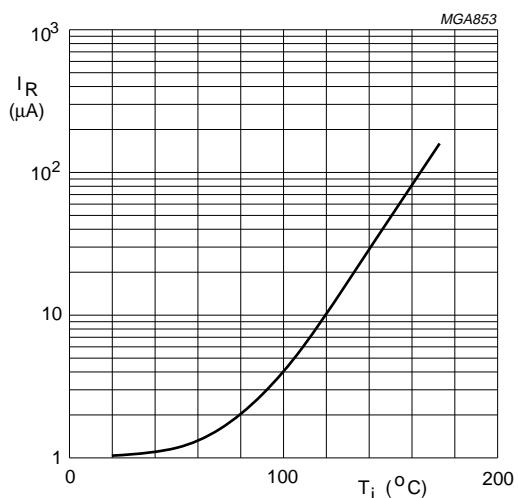
 $V_R = V_{RRMmax}$

Fig.6 Reverse current as a function of junction temperature; maximum values.

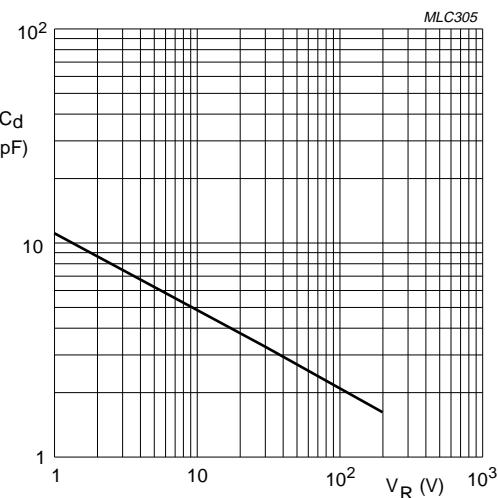
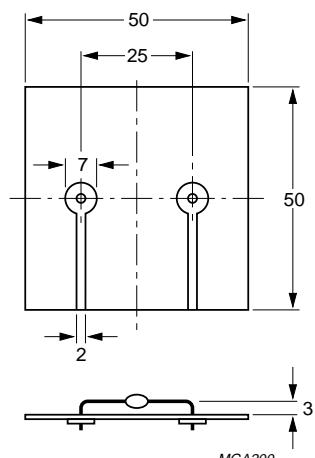
 $f = 1 \text{ MHz}; T_j = 25 \text{ }^{\circ}C$

Fig.7 Diode capacitance as a function of reverse voltage; typical values.



Dimensions in mm.

Fig.8 Device mounted on a printed-circuit board.

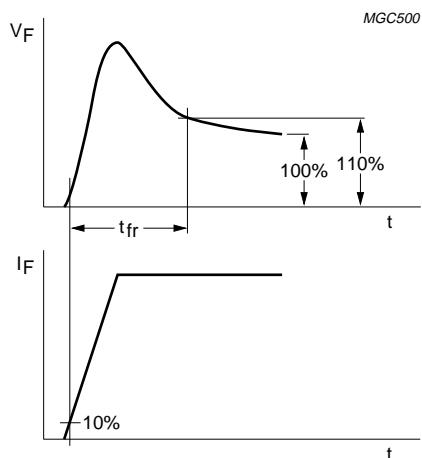
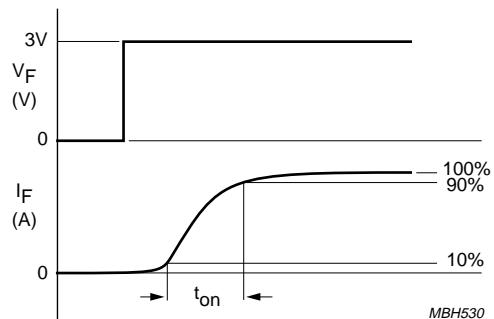
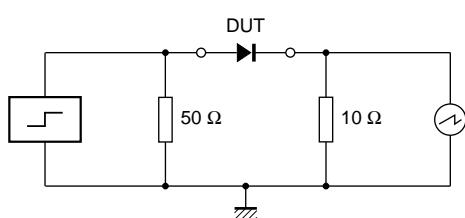


Fig.9 Forward recovery time definition.

Ripple blocking diode

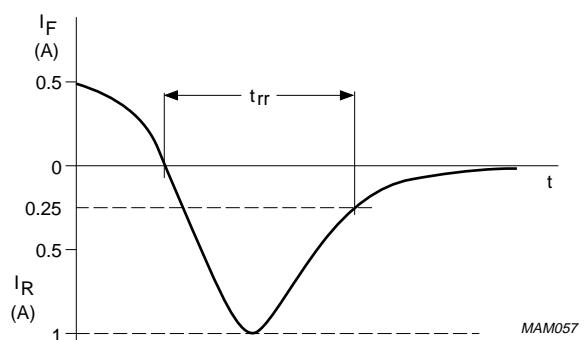
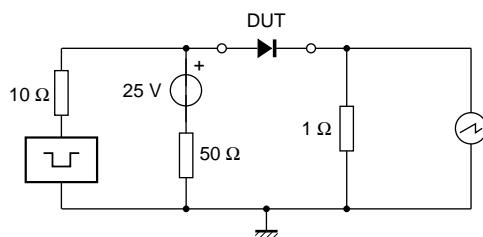
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Input impedance oscilloscope: $1 \text{ M}\Omega$, 22 pF ; $t_r \leq 7 \text{ ns}$.

Source impedance: 50Ω ; $t_r \leq 10 \text{ ns}$.

Fig.10 Test circuit and turn-on time waveform and definition.



Input impedance oscilloscope: $1 \text{ M}\Omega$, 22 pF ; $t_r \leq 7 \text{ ns}$.

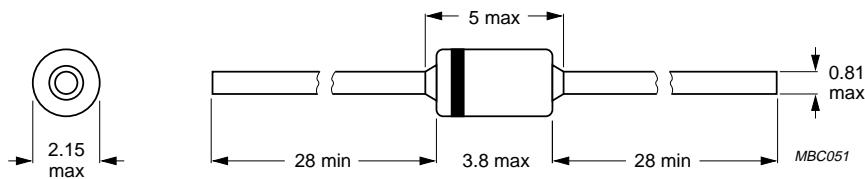
Source impedance: 50Ω ; $t_r \leq 15 \text{ ns}$.

Fig.11 Test circuit and reverse recovery time waveform and definition.

Ripple blocking diode

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PACKAGE OUTLINE



Dimensions in mm.

The marking band indicates the cathode.

Fig.12 SOD81.

DEFINITIONS

Data Sheet Status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

LIFE SUPPORT APPLICATIONS

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